# **Amplifier Transistors**

## **NPN Silicon**

#### **Features**

• Pb-Free Package is Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	BC337	BC338	Unit	
Collector - Emitter Voltage	$V_{CEO}$	45	25	Vdc	
Collector - Base Voltage	$V_{CBO}$	50 30		Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	5.0		Vdc	
Collector Current – Continuous	I <sub>C</sub>	800		mAdc	
Total Device Dissipation  @ T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	625 5.0		mW mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12		W mW/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150		°C	

#### THERMAL CHARACTERISTICS

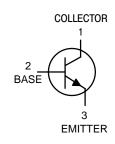
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

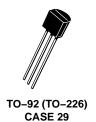
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

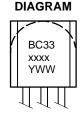


## ON Semiconductor®

#### http://onsemi.com







**MARKING** 

xxxx = Specific Device Code

Y = Year WW = Work Week

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characte	ristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0) BC338	BC337	V <sub>(BR)CE</sub> O	45 25	_ _	- -	Vdc
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 100 μA, I <sub>E</sub> = 0) BC338	BC337	V <sub>(BR)CE</sub>	50 30	- -	- -	Vdc
Emitter – Base Breakdown Voltage ( $I_E = 10 \mu A, I_C = 0$ )		V <sub>(BR)EB</sub>	5.0	-	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ V}, I_E = 0)$ $(V_{CB} = 20 \text{ V}, I_E = 0)$	BC337 BC338	I <sub>CBO</sub>	- -	- -	100 100	nAdc
Collector Cutoff Current ( $V_{CE} = 45 \text{ V}, V_{BE} = 0$ ) ( $V_{CE} = 25 \text{ V}, V_{BE} = 0$ )	BC337 BC338	I <sub>CES</sub>	- -	- -	100 100	nAdc
Emitter Cutoff Current (V <sub>EB</sub> = 4.0 V, I <sub>C</sub> = 0)		I <sub>EBO</sub>	-	-	100	nAdc
ON CHARACTERISTICS						
DC Current Gain ( $I_C = 100$ mA, $V_{CE} = 1.0$ V) ( $I_C = 300$ mA, $V_{CE} = 1.0$ V)	BC337 BC337-16 BC337-25/BC338-25 BC337-40	h <sub>FE</sub>	100 100 160 250 60	- - - -	630 250 400 630	-
Base–Emitter On Voltage (I <sub>C</sub> = 300 mA, V <sub>CE</sub> = 1.0 V)		V <sub>BE(on)</sub>	-	-	1.2	Vdc
Collector – Emitter Saturation Voltage (I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA)		V <sub>CE(sat)</sub>	-	_	0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS						
Output Capacitance (V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>ob</sub>	-	15	-	pF
Current – Gain – Bandwidth Product (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V, f = 100 MHz)		f <sub>T</sub>	-	210	-	MHz

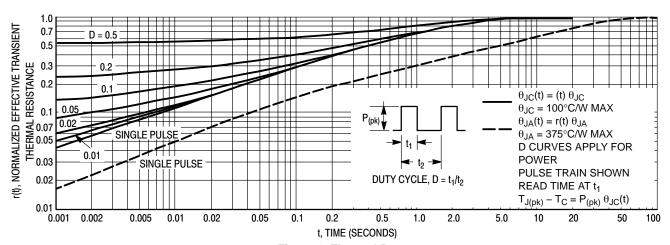


Figure 1. Thermal Response

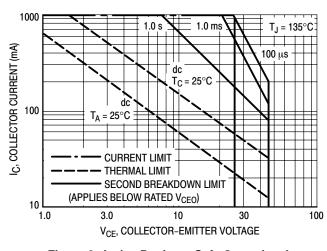


Figure 2. Active Region - Safe Operating Area

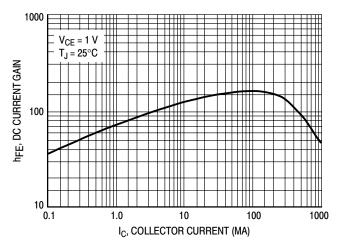


Figure 3. DC Current Gain

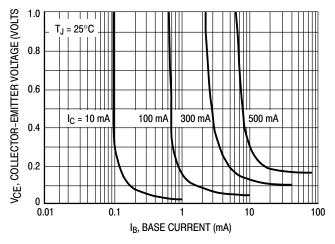


Figure 4. Saturation Region

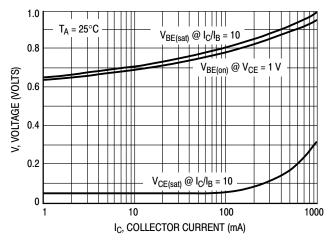
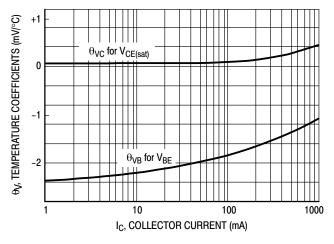


Figure 5. "On" Voltages



**Figure 6. Temperature Coefficients** 

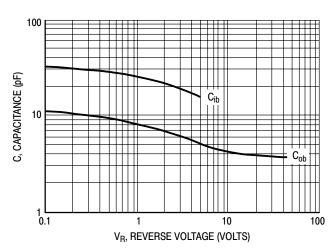


Figure 7. Capacitances

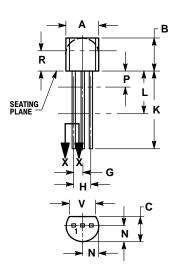
## **ORDERING INFORMATION**

Device	Package	Marking	Shipping <sup>†</sup>
BC337	TO-92	7	5000 Units / Bulk
BC337RL1	TO-92	7	2000 / Tape & Reel
BC337ZL1	TO-92	7	2000 / Tape & Ammunition
BC337-16	TO-92	7–16	5000 Units / Bulk
BC337-16RL1	TO-92	7–16	2000 / Tape & Reel
BC337-16ZL1	TO-92	7–16	2000 / Tape & Ammunition
BC337-25	TO-92	7–25	5000 Units / Bulk
BC337-25RL1	TO-92	7–25	2000 / Tape & Reel
BC337-25ZL1	TO-92	7–25	2000 / Tape & Ammunition
BC337-25ZL1G	TO-92 (Pb-Free)	8–25	2000 / Tape & Ammunition
BC337-40	TO-92	7–40	5000 Units / Bulk
BC337-40RL1	TO-92	7–40	2000 / Tape & Reel
BC337-40ZL1	TO-92	7–40	2000 / Tape & Ammunition
BC338-25ZL1	TO-92	8–25	2000 / Tape & Ammunition

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **PACKAGE DIMENSIONS**

TO-92 (TO-226) CASE 29-11 ISSUE AL





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082–1312 USA Phone: 480–829–7710 or 800–344–3860 Toll Free USA/Canada Fax: 480–829–7709 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800–282–9855 Toll Free LISA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2–9–1 Kamimeguro, Meguro–ku, Tokyo, Japan 153–0051 Phone: 81–3–5773–3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.